# 2N7002L, 2V7002L

# **Small Signal MOSFET**

60 V, 115 mA, N-Channel SOT-23

### Features

- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable (2V7002L)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	60	Vdc
Drain–Gate Voltage ( $R_{GS}$ = 1.0 M $\Omega$ )	V <sub>DGR</sub>	60	Vdc
Drain Current – Continuous $T_C = 25^{\circ}C$ (Note 1) $T_C = 100^{\circ}C$ (Note 1) – Pulsed (Note 2)	I <sub>D</sub> I <sub>D</sub> I <sub>DM</sub>	±115 ±75 ±800	mAdc
Gate–Source Voltage – Continuous – Non–repetitive (t <sub>p</sub> ≤ 50 μs)	V <sub>GS</sub> V <sub>GSM</sub>	±20 ±40	Vdc Vpk

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 3) T <sub>A</sub> = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	P <sub>D</sub> R <sub>θJA</sub>	225 1.8 556	mW mW/°C °C/W
Total Device Dissipation (Note 4) Alumina Substrate, T <sub>A</sub> = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	P <sub>D</sub> R <sub>θJA</sub>	300 2.4 417	mW mW/°C °C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

3. FR-5 = 1.0 x 0.75 x 0.062 in.

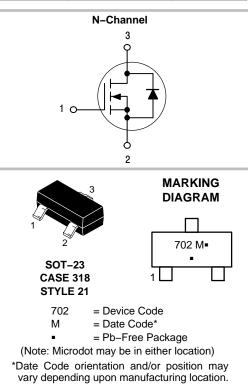
4. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.



## **ON Semiconductor®**

### www.onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> MAX	
60 V	7.5 Ω @ 10 V, 500 mA	115 mA	



### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>		
2N7002LT1G	SOT-23	3000 Tape & Reel		
2N7002LT3G	(Pb-Free)	10,000 Tape & Reel		
2V7002LT1G		3000 Tape & Reel		
2V7002LT3G	SOT-23	10,000 Tape & Reel		
2N7002LT1H*	(Pb-Free)	3000 Tape & Reel		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*Not for new design.

# 2N7002L, 2V7002L

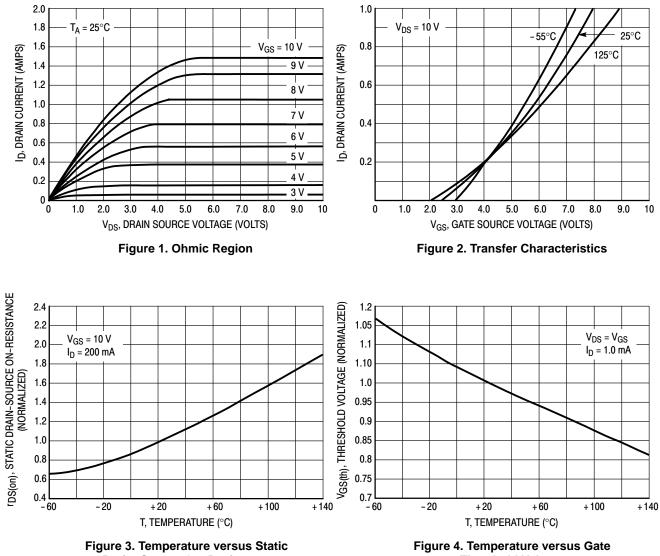
## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Drain–Source Breakdown Voltage $(V_{GS} = 0, I_D = 10 \ \mu Adc)$	V <sub>(BR)DSS</sub>	60	_	-	Vdc
$ \begin{array}{ll} \mbox{Zero Gate Voltage Drain Current} & T_J = 25^\circ C \\ (V_{GS} = 0,  V_{DS} = 60  Vdc) & T_J = 125^\circ C \end{array} $	I <sub>DSS</sub>	-		1.0 500	μAdc
Gate-Body Leakage Current, Forward (V <sub>GS</sub> = 20 Vdc)	I <sub>GSSF</sub>	-	_	100	nAdc
Gate-Body Leakage Current, Reverse (V <sub>GS</sub> = -20 Vdc)	I <sub>GSSR</sub>	-	-	-100	nAdc
ON CHARACTERISTICS (Note 5)	•				•
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$	V <sub>GS(th)</sub>	1.0	-	2.5	Vdc
On–State Drain Current $(V_{DS} \ge 2.0 V_{DS(on)}, V_{GS} = 10 \text{ Vdc})$	I <sub>D(on)</sub>	500	_	_	mA
Static Drain–Source On–State Voltage ( $V_{GS}$ = 10 Vdc, I <sub>D</sub> = 500 mAdc) ( $V_{GS}$ = 5.0 Vdc, I <sub>D</sub> = 50 mAdc)	V <sub>DS(on)</sub>	-		3.75 0.375	Vdc
$ \begin{array}{l} \mbox{Static Drain-Source On-State Resistance} \\ (V_{GS} = 10 \ V, \ I_D = 500 \ mAdc) \\ (V_{GS} = 5.0 \ Vdc, \ I_D = 50 \ mAdc) \\ T_C = 25^{\circ}C \\ T_C = 125^{\circ}C \\ T_C = 125^{\circ}C \\ T_C = 125^{\circ}C \end{array} $	r <sub>DS(on)</sub>	- - -		7.5 13.5 7.5 13.5	Ohms
Forward Transconductance $(V_{DS} \ge 2.0 V_{DS(on)}, I_D = 200 \text{ mAdc})$	9fs	80	-	-	mS
DYNAMIC CHARACTERISTICS					
Input Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C <sub>iss</sub>	-	-	50	pF
Output Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C <sub>oss</sub>	-	-	25	pF
Reverse Transfer Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C <sub>rss</sub>	-	-	5.0	pF
SWITCHING CHARACTERISTICS (Note 5)					
Turn–On Delay Time $(V_{DD} = 25 \text{ Vdc}, I_D \cong 500 \text{ mAdc},$	t <sub>d(on)</sub>	-	-	20	ns
Turn–Off Delay Time $R_G = 25 \Omega$ , $R_L = 50 \Omega$ , $V_{gen} = 10 V$ )	t <sub>d(off)</sub>	-	-	40	ns
BODY-DRAIN DIODE RATINGS					
Diode Forward On–Voltage $(I_S = 11.5 \text{ mAdc}, V_{GS} = 0 \text{ V})$	$V_{SD}$	-	-	-1.5	Vdc
Source Current Continuous (Body Diode)	۱ <sub>S</sub>	-	-	-115	mAdc
Source Current Pulsed	I <sub>SM</sub>	_	-	-800	mAdc

5. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

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## **TYPICAL ELECTRICAL CHARACTERISTICS**

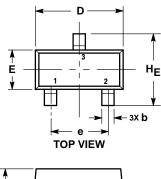


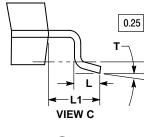
Drain-Source On-Resistance

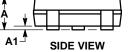
**Threshold Voltage** 

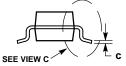
#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AR









END VIEW

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

 MAXIMUM LEAD THICKNESS INCLUDERS LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL

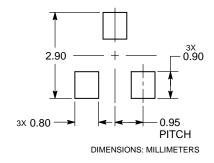
THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

STYLE 21: PIN 1. GATE

2. SOURCE 3. DRAIN

#### RECOMMENDED SOLDERING FOOTPRINT



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